

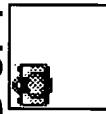
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Status: 93 - NOTICE OF ALLOWANCE MAILED -- APPLICATION RECEIVED IN OFFICE OF PUBLICATIONS
Title: SEMICONDUCTOR MEMORY INCLUDING STATIC RANDOM ACCESS MEMORY FORMED OF FINFET

GAU: 2824

Examiner: NGUYEN, DANG
Inventor: WATANABE , TAKESHI, et al
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Bib Data report

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Inventors:
Last name, First name: City: Country or State: